

Columnar Self-Assembly of Cu₂S Hexagonal Nanoplates Induced by Tin(IV)–X Complex as Inorganic Surface Ligand

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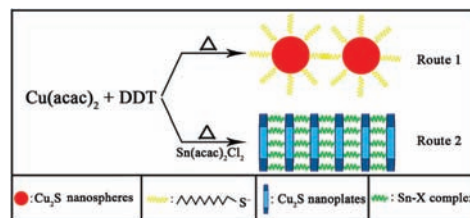
Abstract: We have prepared columnar self-assembled Cu₂S hexagonal nanoplates induced by a Sn–X complex for the first time and demonstrated that the Sn–X complex can affect not only the morphology of the nanocrystals but also the self-assembly ability of the nanocrystals.

The bottom-up colloid chemical synthesis of various inorganic nanocrystals with well-defined size, shape, and composition has achieved great success over the past two decades.¹ Because of their extraordinary physical and chemical properties, colloidal inorganic nanocrystals have shown potential applications in light-emitting devices, photodetectors, solar cells, and other devices.¹ With the further development of synthetic methodologies, the design and construction of nanocrystal superlattices, which is the basis of nanomaterials and nanodevices, has begun to attract great interest in both fundamental and applied research areas.² To achieve this goal, the self-assembly technique has been widely used because of its distinct advantages, such as simplicity and low cost. Surface ligands are usually organic compounds with long hydrocarbon chains,³ and the insulating nature of such organic ligands typically results in very poor interparticle coupling. Most recently, Talapin and co-workers⁴ found that various molecular metal chalcogenide complexes (MCCs), such as [Sn₂S₆]^{4–} and [Sn₂Se₆]^{4–}, could serve as convenient ligands for colloidal nanocrystals and nanowires. The MCC ligands behaved as electronically transparent “glue” for nanocrystals. With various special properties, inorganic ligands may open an innovative way to device-level manipulation of MCC-nanocrystals and benefit many nanocrystal-related potential applications. Furthermore, they may also influence the self-assembly ability and morphology of nanocrystals as organic ligands do.

As a p-type semiconductor with a bulk band gap of 1.2 eV, copper(I) sulfide (Cu₂S) has many applications in solar cells,^{1h} cold cathodes,¹ⁱ and nanoscale switches.^{1j} In this communication, we report the columnar self-assembly of Cu₂S hexagonal nanoplates induced by a tin(IV) sulfide complex (Sn–X complex) that was formed by the reaction between tin(IV) bis(acetylacetonate) dichloride [Sn(acac)₂Cl₂] and excess 1-dodecanethiol (DDT). As shown in Scheme 1, when copper(II) acetylacetonate [Cu(acac)₂] reacted with DDT, only DDT-capped Cu₂S nanospheres were synthesized. Columnar self-assembled hexagonal Cu₂S nanoplates were synthesized once Sn(acac)₂Cl₂ was involved in the reaction. This indicated that the Sn–X complex did play an important role in controlling the shape of the Cu₂S nanocrystals, which further influenced their self-assembly ability.

Figure 1A,B shows transmission electron microscopy (TEM) images of the two different kinds of morphologies of Cu₂S nanocrystals formed without and with the participation of

Scheme 1. Synthetic Procedure for Cu₂S Nanospheres and Cu₂S Hexagonal Nanoplates with Columnar Self-Assembly



Sn(acac)₂Cl₂ in the reaction, respectively. Nearly monodisperse Cu₂S nanospheres were prepared in the absence of Sn(acac)₂Cl₂ (also see Figure S1 in the Supporting Information), while the shape of the Cu₂S nanocrystals was totally different when Sn(acac)₂Cl₂ was introduced. As shown in Figure 1B, these Cu₂S nanocrystals had a strong self-assembling tendency, and at first glance, one-dimensional (1D) superstructures were formed by the arrays of many nanorods. However, careful observation revealed that the building blocks of the 1D superstructures were in fact hexagonal nanoplates. The areas marked by blue and red rectangles in Figure 2A show upright and tilted hexagonal nanoplates, respectively, and clearly reveal that the 1D superstructures of Cu₂S nanocrystals were composed of hexagonal nanoplates stacking face-to-face. The high-resolution TEM (HRTEM) image of the ordered hexagonal nanoplate arrays standing edge-on perpendicular to the substrate (Figure 1C) shows a lattice spacing of 3.39 Å, which is consistent with the (004)-plane *d* spacing of monoclinic primitive Cu₂S. In other words, the nanoplates assembled with their {001} planes perpendicular to

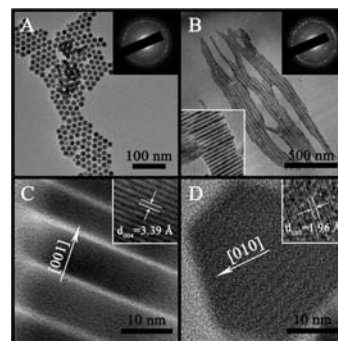


Figure 1. (A) TEM images of as-synthesized DDT-capped circular Cu₂S nanospheres synthesized by route 1. The inset shows the selected-area electron diffraction (SAED) pattern. (B) TEM image of as-synthesized Cu₂S nanoplates with columnar self-assembly synthesized by route 2. The insets show the SAED pattern and a high magnification of the selected area. (C) HRTEM image of the ordered hexagonal nanoplate arrays standing edge-on perpendicular to the substrate. (D) HRTEM image of a hexagonal nanoplate lying flat on the substrate.

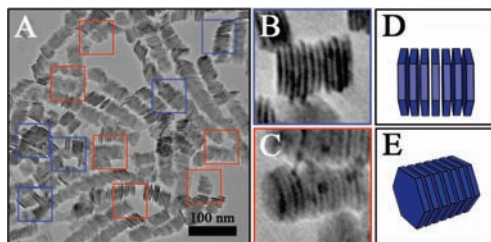


Figure 2. (A) TEM images of typical Cu_2S nanoplates with columnar self-assembly synthesized by route 2 at 200°C for 30 min. Blue and red rectangles indicate the upright and tilted hexagonal nanoplates, respectively. (B, C) High-magnification TEM images and (D, E) illustrations of the upright and tilted hexagonal nanoplates.

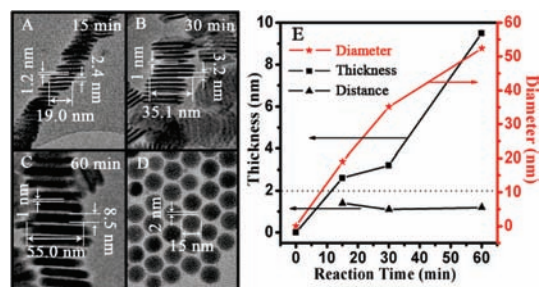


Figure 3. Feature TEM images of (A–C) typical columnar self-assembly of hexagonal Cu_2S nanoplates synthesized by route 2 at different reaction times and (D) Cu_2S nanospheres synthesized by route 1. (E) Evolution of the diameter (red ★) and thickness (black ■) of the Cu_2S nanoplates and the distance between two adjacent face-to-face nanoplates (black ▲).

the substrate, which is in agreement with the literature.⁵ Figure 1D shows an HRTEM image of a single hexagonal nanoplate lying flat on its hexagonal facet. It can be seen that the lattice spacing is 1.96 \AA , corresponding to the (080)-plane d spacing of monoclinic primitive Cu_2S . Upon adjustment of the experimental parameters, the as-synthesized Cu_2S hexagonal nanoplates self-assembled into large-scale 1D and 3D columns (Figures S2–S4).

Further experiments revealed that the size of the 1D-superstructured hexagonal Cu_2S nanoplates could be tuned simply by changing the reaction time (Figure 3 and Figure S5). When the reaction time was 15 min, the platelet particles had an average diameter of 19 nm with an average thickness of 2.4 nm. Superstructures were still maintained after 60 min of reaction, while the diameter and thickness of hexagonal nanoplates were increased to ~ 55 nm and ~ 9.5 nm, respectively. Even though the particle size grew larger with prolonged reaction time, the distance between two adjacent face-to-face stacked nanoplates kept a fixed value (~ 1.0 nm). This value was much smaller than that of DDT-capped circular Cu_2S nanospheres, whose average spacing was ~ 2 nm (Figure 3D), which is consistent with the literature and theoretical values ($1.9 \text{ nm} < d < 3.8 \text{ nm}$).^{2d,6,7} In comparison with the interparticle spacing of DDT-capped circular Cu_2S nanospheres, the ligands capping the hexagonal nanoplates should be shorter ligands related to the Sn–X complex on the basis of the analysis from FTIR, XPS, and UV–vis spectra (Figures S6–S8). The electric transport properties of Cu_2S nanocrystals with and without the participation of the Sn–X complex were also studied (Figure S9). The as-synthesized DDT-capped nanocrystals showed low conductivity as a result of the large interparticle spacing (~ 2.0 nm) connected by the insulating DDT molecules. The conductivity of the self-assembled nanoplates, however, was improved nearly 1 order of magnitude because of the short interparticle spacing (~ 1.0 nm) linked by the Sn–X complex.

According to the results of control experiments and characterizations, we assume that there are two main probabilities resulting in the columnar assembly: first, in accordance with the literature,⁵ the platelet shape of the nanocrystals may easily lead to the formation of columnar assemblies; second, the Sn–X complex should have a special structure whose two ends could both bind to the surface of hexagonal nanoplates, so the nanoplates could stack face-to-face and form a columnar self-assembled structure. Similar results could also be observed when other Sn(IV) salts (such as SnCl_4) were used (Figure S10). According to literature reported by Talapin,⁴ the Sn–X complex in the form of $[\text{Sn}_2\text{S}_6]^{4-}$ is proposed, as shown in Scheme 1 (green ligands); however, an in-depth investigation of the exact structure of the Sn–X complex is still in progress.

In summary, we have prepared columnar self-assembled Cu_2S hexagonal nanoplates induced by a Sn–X complex for the first time and demonstrated that the Sn–X complex can affect not only the morphology of the nanocrystals (as traditional organic ligands do) but also the self-assembly ability of the nanocrystals. We believe that the methodology of constructing self-assembled nanostructures reported in this communication may turn over a new leaf in device-level manipulation of nanocrystals and many nanocrystal-related potential applications.

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Supporting Information Available: Experimental details, results and discussion on Cu_2S nanospheres, and 1D and 3D columnar self-assembly of hexagonal Cu_2S nanoplates and Sn–X complexes. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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